

Green Products

20SQ045 SCHOTTKY BARRIER RECTIFIER

Applications:

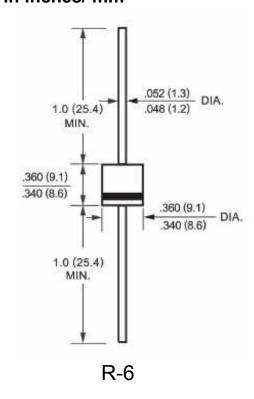
- DC-DC converters
- AC adapter
- High frequency rectification circuit
- Bypass diodes
- Photovoltaic Solar cell Protection Schottky Rectifier

Features:

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In Inches/ mm



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Marking Diagram:



Where XXXXX is YYWWL

= Forward Current (20A)

S = Package Type Q = Device Type

045 = Reverse Voltage (45V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
20SQ045	R-6 (Pb-Free)	500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Rating:

Characteristics	Symbol	Symbol Conditions		Unit
Repetitive Peak Reverse Voltage	VRRM	-	45	V
Max. average forward current	I _{F(AV)}	R- load, Ta=25℃	20	Α
Surge(Non-repetitive) Forward Current	I _{FSM}	8.3ms single half sine-wave	350	A

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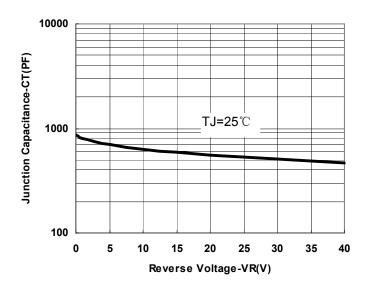
Electrical Characteristics (Ta=25℃ Unless otherwise specified)

Characteristics	Symbol	Conditions		Max.	Unit
Peak Forward Voltage	VFM	IFM=20.0A,Ta=25℃		0.55	V
Peak Reverse Current	IRRM1	VRM=VRRM	Ta=25℃	0.5	mA
	IRRM2	VRM-VRRM	Ta=100℃	50	IIIA
Thermal Resistance(Typical)	R θJ-c	Between junction and case		3.0	°C/W
	R θJ-L	Between june	ction and lead	2.0	CIVV

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode	TJ	$V_{R}{\leqslant}80\%V_{RRM} \ V_{R}{\leqslant}50\%V_{RRM}$	-55 to +150 -55 to +180 -55 to +200	°C
Max. Storage Temperature	T_{stg}	-	-55 to +150	°C
Approximate Weight	wt	-	2.24	g
Case Style		R-6		

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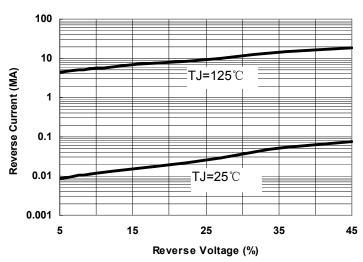


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

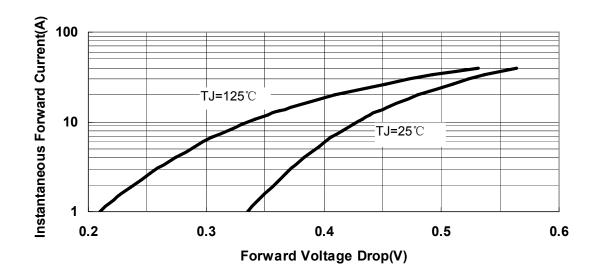


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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